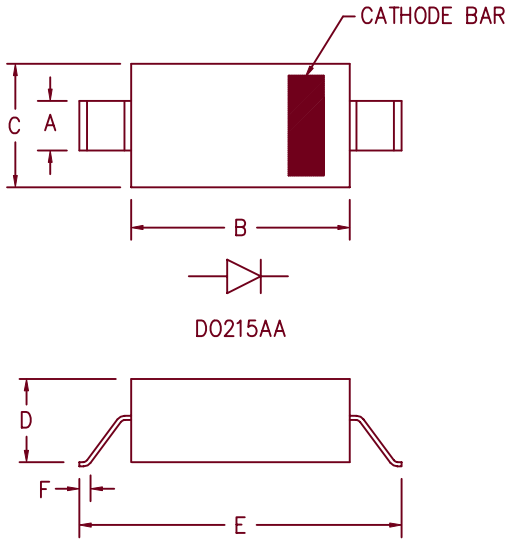
1 Amp Schottky Rectifier

HSM180G – HSM1100G



Dim.	Inches		Millimeter		
	Minimum	Maximum	Minimum	Maximum	Notes
A	.081	.087	2.06	2.21	
B	.160	.180	4.06	4.57	
C	.130	.155	3.30	3.94	
D	.075	.095	1.90	2.41	
E	.270	.290	6.86	7.37	
F	.015	.030	.381	.762	

Microsemi Catalog Number	Working Peak Reverse Voltage	Repetitive Peak Reverse Voltage
HSM180	80V	80V
HSM190	90V	90V
HSM1100	100V	100V

- Schottky Barrier Rectifier
- Guard Ring Protection
- 175°C Junction Temperature
- V_{RRM} 80 to 100 Volts
- Economical Surface Mount Package

Electrical Characteristics

Average forward current	$I_{F(AV)}$ 1.0 Amps	Square wave
Maximum surge current	I_{FSM} 40 Amps	8.3ms, half sine, T_J = 150°C
Max peak forward voltage	V_{FM} .57 Volts	I_{FM} = 0.1A; T_J = 25°C*
Max peak forward voltage	V_{FM} .84 Volts	I_{FM} = 1.0A; T_J = 25°C*
Max peak reverse current	I_{RM} 100 µA	V_{RRM}, T_J = 25°C
Typical junction capacitance	C_J 45pF	V_R = 5.0V, T_J = 25°C

*Pulse test: Pulse width 300 µsec, Duty cycle 2%

Thermal and Mechanical Characteristics

Storage temperature range	T_{STG}	−55°C to 175°C
Operating junction temp range	T_J	−55°C to 175°C
Maximum thermal resistance	$R_{\Theta JL}$	25°C/W Junction to lead
Weight		.0047 ounces (.013 grams) typical

3–28–00 Rev. IR

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Figure 1
Typical Forward Characteristics

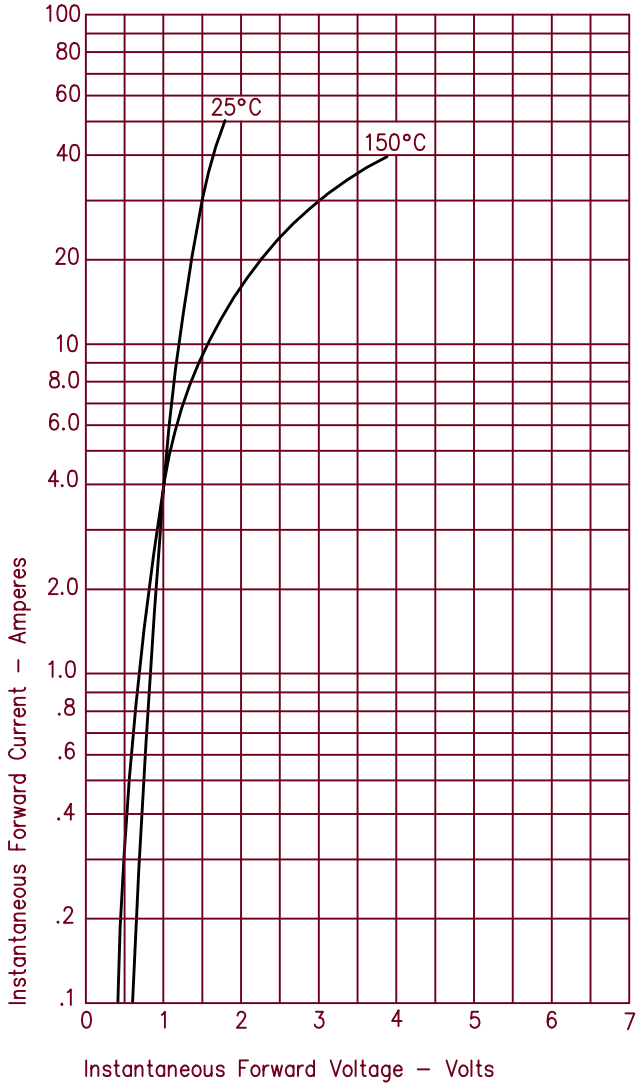


Figure 2
Typical Reverse Characteristics

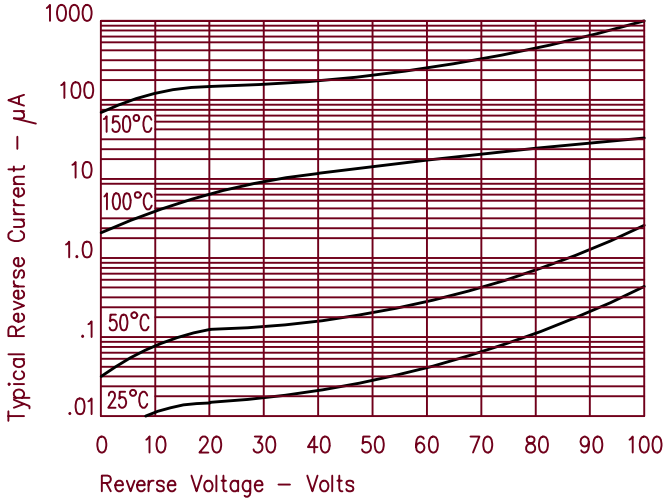
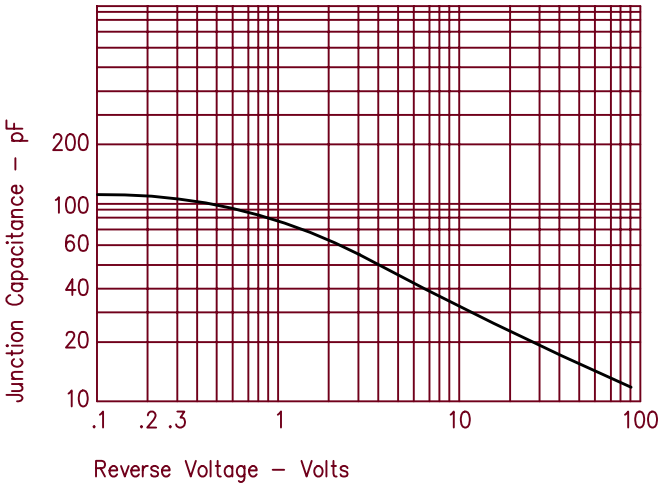


Figure 3
Typical Junction Capacitance



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